

LED Driver with Adjustable Current

Features

- Adjustable constant output current
- Wide input voltage range
- Low drop voltage
- Open load detection
- Overtemperature protection
- Short circuit proof
- Reverse polarity proof
- Wide temperature range: -40 °C < T_i < 150 °C
- Very small SMD-Package

Functional Description



The **TLE 4241 GM** is an integrated adjustable constant current source. It provides an output current adjustable via different means (SET, PWM, reference resistor) which is kept nearly independent from load and supply voltage changes. The IC is designed to supply LEDs under the severe conditions of automotive applications resulting in constant brightness and extended LED lifetime. It is provided in the very small P-DSO-8-9 (Micro 8) package. Protection circuits prevent damage to the device in case of overload, short circuit, reverse polarity and overtemperature. The connected LEDs are protected against reverse polarity as well as excess voltages up to 45 V. A status output allows handling of open load and short circuit at the main output.

A PWM input offers the possibility to adjust the LED brightness by pulse width modulation.

With an implemented high/low current switch the output current level can be reduced e.g. for brake/tail light application.

The implemented features such as adjustable output current, the high/low current switch and the provided PWM input make the device well suited for a broad range of LED and other applications.

Туре	Ordering Code	Package
TLE 4241 GM	Q67006-A9644	P-DSO-8-9



Circuit Description



Figure 1 Block Diagram

An internal reference voltage of typ. 1.20 V supplies the REF pin which is connected to GND via an external resistor. In the SET = H mode the reference current flowing on the REF pin is mirrored with an amplification to form the desired output current. The typ. output current in the SET = H mode calculates:

$$I_{\rm Q, \, typ}/{\rm mA} = \frac{1.20}{R_{\rm REF}/{\rm k}\Omega} \times 487 + 0.1$$
 (1)

The output current is shown as a function of the reference resistance on **Page 10** for the high as well as for the low current mode.

With the PWM input the LED brightness can be regulated via duty cycle. Also PWM = L sets the TLE 4241 in sleep mode resulting in a very low current consumption of << 1 μ A typ. Due to the high impedance of the PWM input (see timing diagram I_{PWM} versus V_{PWM} on **Page 12**) the PWM pin can thus also be used as an Enable input.





Figure 2	Pin Configuration (top view)
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Table 1	Pin Definitions and Functions					
Pin No.	Symbol	Function				
1	GND	Ground; internally connected to pin 5				
2	ST	Status Output; open collector output, connect to external pull-up resistor (10 k Ω or higher)				
3	PWM	Pulse Width Modulation Input; if not needed connect to V ₁				
4	SET	High/Low Current Input; choice of current level				
5	GND	Ground; internally connected to pin 1				
6	REF	Reference Input; connect to GND via an external resistor to adjust the output current				
7	Q	Output				
8	I	Input; block to GND directly at the IC with a 100 nF ceramic capacitor				

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Application Information



Figure 3 Application Circuit

Figure 3 shows a typical application with the TLE 4241 GM LED driver. The 3 LEDs are driven with an adequate supply current adjusted by the resistor R_{REF} . Thus brightness variations due to forward voltage spread of the LEDs are prevented. The luminosity spread arising from the LED production process can be compensated via software by an appropriate duty cycle applied to the PWM pin. Hence selection of the LEDs to forward voltage as well as to luminosity classes can be spared. The slightly negative temperature coefficient of the TLE 4241 GM output current protects the LEDs against overtemperature stress if the IC is placed nearby the LEDs.

The voltage drop ($V_{\rm l} - V_{\rm Q}$) across the TLE 4241 GM is monitored in order to detect an open load condition indicated at the status output pin ST. In case of open load, the voltage drop will decrease below the lower status switching threshold $V_{\rm dr,L}$. Hence, the status output ST will be driven low. In normal operation, the voltage drop is above the upper status threshold $V_{\rm dr,H}$, thus the open collector output ST is in high-ohmic state (see also section Status Output at the Electrical Characteristics).

The function of ST, SET and PWM as well as their timings are shown in Figure 4.





Figure 4

Function and Timing Diagram



Table 2 Absolute Maximum Ratings

-40 °C < *T*_j < 150 °C

Parameter	Symbol	Limit Values		Unit	Remarks	
		Min.	Max.	1		
Input		1	- 4			
Voltage	$V_{\rm I}$	-42	45	V	-	
Current	I	-	_	mA	internally limited	
Output						
Voltage	V_{Q}	-1	40	V	-	
Current	IQ	-	-	mA	internally limited	
Status Output				•		
Voltage	$V_{\rm ST}$	-0.3	40	V	-	
Current	I _{ST}	- 5	5	mA	internally limited	
Reference Input						
Voltage	V_{REF}	-0.3	7	V	-	
Current	I _{REF}	-2	2	mA	-	
Pulse Width Modulation In	put	1				
Voltage	V_{PWM}	-40	40	V	-	
Current	-	-1	1	mA	-	
High/Low Current Input	!	1				
Voltage	V_{SET}	-40	40	V	-	
Current	I_{SET}	-1	1	mA	-	
Temperatures	!	1				
Junction temperature	Tj	T _i -40 150 °C –		-		
Storage temperature	T _{stg}	-50	150	°C	-	
Thermal Resistances		1	- 1			
Junction ambient	$R_{ m thja}$	-	105	K/W	1)	

1) Worst case regarding peak temperature; mounted on PCB $80 \times 80 \times 1.5 \text{ mm}^3$, $35 \ \mu\text{m}$ Cu, $300 \ \text{mm}^2$ heat sink area.

Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.



Table 3Operating Range

Parameter	Symbol	Limi	t Values	Unit	Remarks
		Min.	Max.		
Input voltage	$V_{\rm I}$	4	45	V	-
Status output voltage	$V_{\rm ST}$	-	16	V	-
SET voltage	V_{SET}	0	40	V	-
PWM voltage	V_{PWM}	0	40	V	-
Junction temperature	Tj	-40	150	°C	-
Reference Resistor	R _{REF}	7	100	kΩ	SET = H
		4.7	18	kΩ	SET = L



Table 4 Electrical Characteristics

9 V $\leq V_{\rm I} \leq$ 16 V; $R_{\rm REF}$ = 10 kΩ; $V_{\rm PWM} \geq V_{\rm PWM,H}$; -40 °C < $T_{\rm j}$ < 150 °C; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition	
		Min. Typ.		Max.			
Current consumption off mode	$I_{\rm qOFF}$	-	0.1	2	μA	PWM = L, T_J < 85 °C; $V_I \le$ 13.5 V	
Current consumption	I _{qL}	-	5	10	mA	SET = L; V_Q = 6 V	
Current consumption	I _{qH}	-	6	10	mA	SET = H; V_Q = 6 V	
Current consumption open load	$I_{\rm qL,O}$	-	-	10	mA	SET = L; V_{Q} open	
Current consumption open load	I _{qH,O}	-	-	10	mA	SET = H; V_{Q} open	
Output							
Output current	I _Q	6.7	8.4	10	mA	SET = L, $V_{\rm Q}$ = 6 V	
		-	8.6	-	mA	SET = L, V_Q = 4 V	
Output current	I_{Q}	47	58.5	70	mA	SET = H, $V_{\rm Q}$ = 6 V	
		-	60.0	-	mA	SET = H, V_Q = 4 V	
Current Ratio	$I_{\rm QH}/I_{\rm QL}$	6	7	8	-	-	
Output current limit	I _{Qmax}	-	83	-	mA	SET = L; $R_{\text{REF}} = 0 \ \Omega$	
Output current limit	$I_{\rm Qmax}$	-	83	-	mA	SET = H; R_{REF} = 0 Ω	
Drop voltage	V_{dr}	-	0.2	0.5	V	SET = L; I_Q = 80% of $I_{Q,nom,L}$	
Drop voltage	V_{dr}	-	0.3	0.5	V	SET = H; I_Q = 80% of $I_{Q,nom,H}$	
PWM Input							
PWM high level	$V_{\rm PWM,H}$	2.0	-	-	V	-	
PWM low level	$V_{\rm PWM,L}$	-	-	0.5	V	-	
PWM input current high level	I _{PWM,H}	-	220	500	μΑ	V _{PWM} = 5.0 V	
PWM input current low level	$I_{\rm PWM,L}$	-10	-	10	μA	$V_{\rm PWM}$ = 0.0 V	
Turn on delay time	t _{PWM,ON}	0	5	30	μS	20%/80% <i>I</i> _Q , see Figure 4	



Table 4 Electrical Characteristics (cont'd)

9 V $\leq V_{\rm I} \leq$ 16 V; $R_{\rm REF}$ = 10 kΩ; $V_{\rm PWM} \geq V_{\rm PWM,H}$; -40 °C < $T_{\rm j}$ < 150 °C; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition	
		Min. Typ. Ma		Max.	1		
Turn off delay time	t _{PWM,OFF}	0	10	30	μS	20%/80% <i>I</i> _Q , see Figure 4	
SET Input							
SET high level	$V_{\rm SET,H}$	2.0	-	-	V	-	
SET low level	$V_{\rm SET,L}$	-	-	0.5	V	-	
SET input current high level	I _{SET,H}	-	220	500	μA	$V_{\rm SET}$ = 5.0 V	
SET input current low level	$I_{\rm SET,L}$	-10	-	10	μA	$V_{\rm SET}$ = 0.0 V	
Delay time L -> H	t _{SET,H}	-	-	30	μS	20%/80% <i>I</i> _Q , see Figure 4	
Delay time H -> L	t _{SET,L}	-	-	30	μS	20%/80% <i>I</i> _Q , see Figure 4	
Status Output							
Lower status switching threshold	$V_{\rm dr,L}$	0.15	-	-	V	$(V_{\rm l} - V_{\rm Q})$ decreasing SET = L	
		0.15	-	-	V	$(V_{\rm I} - V_{\rm Q})$ decreasing SET = H	
Upper status switching threshold	$V_{\rm dr,H}$	-	-	0.7	V	$(V_1 - V_Q)$ increasing SET = L	
		-	-	0.7	V	$(V_1 - V_Q)$ increasing SET = H	
Status low voltage	$V_{\rm STL}$	-	-	0.4	V	$(V_{\rm I}$ - $V_{\rm Q}) < V_{\rm dr,L}$ $I_{\rm ST}$ = 1.0 mA	
Leakage current	I _{STLK}	-	-	10	μΑ	$(V_{\rm I} - V_{\rm Q}) > V_{\rm dr,H}$ $V_{\rm ST} = 5.0 \text{ V}$	



Output Current versus External Resistor, SET = H

Infineon



Output Current versus Supply Voltage, SET = H



Output Current versus External Resistor, SET = L



Output Current versus Supply Voltage, SET = L





Reference Voltage versus Junction Temperature





PWM Pin Input Current versus PWM Voltage



SET Pin Input Current versus SET Voltage



PWM Pin Input Current versus PWM Voltage



SET Pin Input Current versus SET Voltage





Package Outlines



Figure 5 P-DSO-8-9 (Plastic Dual Small Outline)

You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": http://www.infineon.com/products.

SMD = Surface Mounted Device

Dimensions in mm





Revision History

TLE 4241 GM

Version	Date	Changes
Rev. 1.2	2004-04-13	Page 4, 9: Improved indication and explanation of the open load detection function.

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